

SANYO Semiconductors DATA SHEET

N-Channel Silicon MOSFET

CPH3441— General-Purpose Switching Device Applications

Features

- · Low ON-resistance.
- · Ultrahigh-speed switching.
- · 4V drive.

Specifications

Absolute Maximum Ratings at Ta=25°C

Parameter	Symbol	Conditions	Ratings	Unit
Drain-to-Source Voltage	VDSS		30	V
Gate-to-Source Voltage	VGSS		±20	V
Drain Current (DC)	ID		6.5	Α
Drain Current (Pulse)	IDP	PW≤10μs, duty cycle≤1%	26	Α
Allowable Power Dissipation	PD	Mounted on a ceramic board (900mm ² X0.8mm)	1.2	W
Channel Temperature	Tch		150	°C
Storage Temperature	Tstg		-55 to +150	°C

Electrical Characteristics at Ta=25°C

Parameter	Symbol	Conditions	Ratings			Linit
			min	typ	max	Unit
Drain-to-Source Breakdown Voltage	V(BR)DSS	ID=1mA, VGS=0V	30			V
Zero-Gate Voltage Drain Current	IDSS	V _{DS} =30V, V _{GS} =0V			1	μΑ
Gate-to-Source Leakage Current	IGSS	V _{GS} =±16V, V _{DS} =0V			±10	μΑ
Cutoff Voltage	VGS(off)	VDS=10V, ID=1mA	1.2		2.6	V
Forward Transfer Admittance	yfs	V _{DS} =10V, I _D =3A	3.5	5.7		S
Static Drain-to-Source On-State Resistance	R _{DS} (on)1	I _D =3A, V _G S=10V		19	25	mΩ
	RDS(on)2	ID=1.5A, VGS=4V		36	50	mΩ
Input Capacitance	Ciss	V _{DS} =10V, f=1MHz		994		pF
Output Capacitance	Coss	V _{DS} =10V, f=1MHz		153		pF
Reverse Transfer Capacitance	Crss	VDS=10V, f=1MHz		126		pF
Turn-ON Delay Time	t _d (on)	See specified Test Circuit.		15		ns
Rise Time	t _r	See specified Test Circuit.		28		ns
Turn-OFF Delay Time	t _d (off)	See specified Test Circuit.		77		ns
Fall Time	tf	See specified Test Circuit.		47		ns

Marking: ZQ Continued on next page.

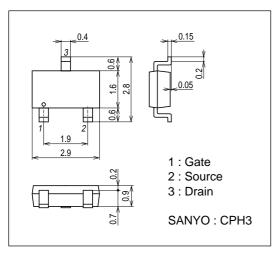
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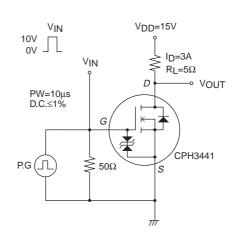
Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	Oill
Total Gate Charge	Qg	V _{DS} =10V, V _{GS} =10V, I _D =6.5A		19.8		nC
Gate-to-Source Charge	Qgs	V _{DS} =10V, V _{GS} =10V, I _D =6.5A		3.6		nC
Gate-to-Drain "Miller" Charge	Qgd	V _{DS} =10V, V _{GS} =10V, I _D =6.5A		3.7		nC
Diode Forward Voltage	VSD	IS=6.5A, VGS=0V		0.85	1.2	V

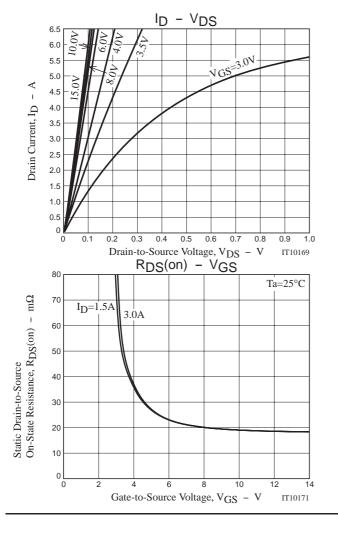
Package Dimensions

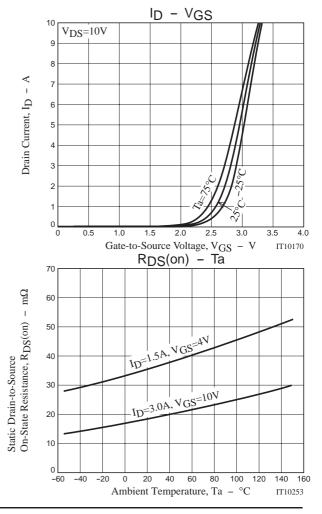
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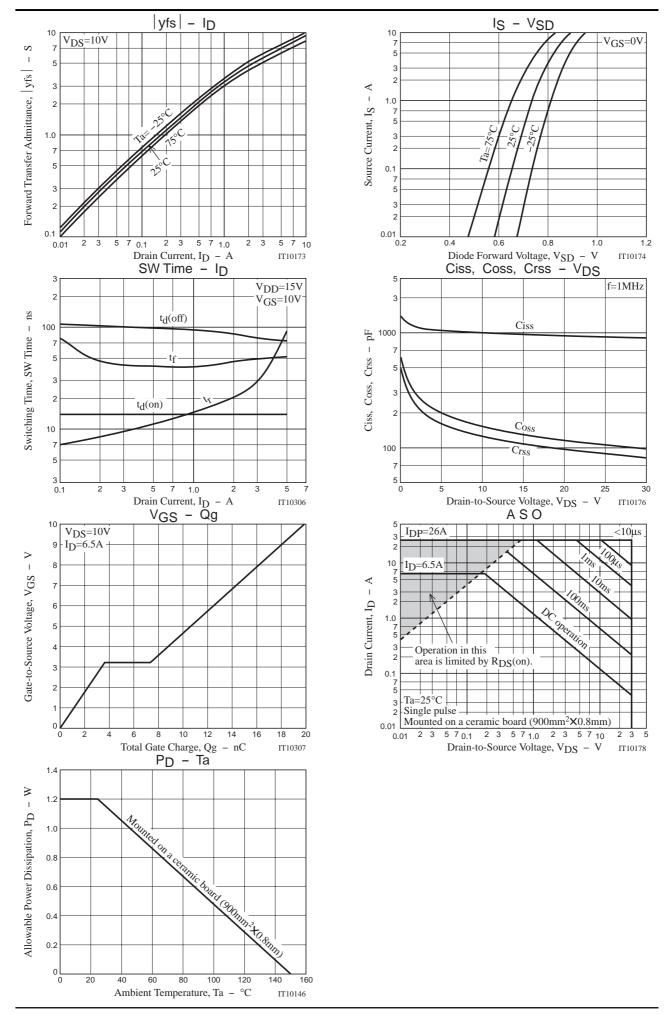


Switching Time Test Circuit









Note on usage: Since the CPH3441 is a MOSFET product, please avoid using this device in the vicinity of highly charged objects.

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